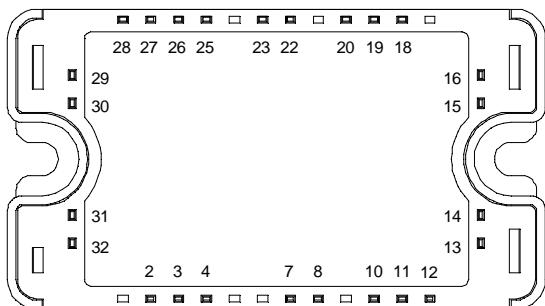
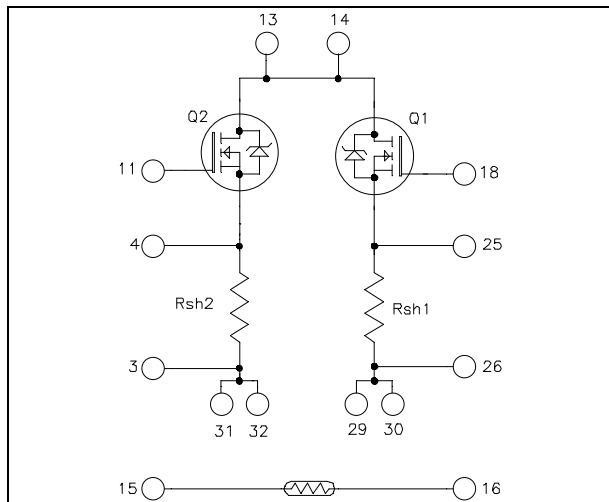


## Linear MOSFET Power Module

**V<sub>DSS</sub> = 500V**  
**R<sub>DSon</sub> = 90mΩ typ @ T<sub>j</sub> = 25°C**  
**I<sub>D</sub> = 52A\* @ T<sub>c</sub> = 25°C**



Pins 13/14 ; 29/30 ; 31/32 must be shorted together

### Absolute maximum ratings (per leg)

Symbol	Parameter	Max ratings	Unit
V <sub>DSS</sub>	Drain - Source Breakdown Voltage	500	V
I <sub>D</sub>	Continuous Drain Current	T <sub>c</sub> = 25°C	A
		T <sub>c</sub> = 80°C	
I <sub>DM</sub>	Pulsed Drain current	200	
V <sub>GS</sub>	Gate - Source Voltage	±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance	108	mΩ
P <sub>D</sub>	Maximum Power Dissipation ①	T <sub>c</sub> = 25°C	W
I <sub>AR</sub>	Avalanche current (repetitive and non repetitive)	52	A
E <sub>AR</sub>	Repetitive Avalanche Energy	50	
E <sub>AS</sub>	Single Pulse Avalanche Energy	3000	mJ

\* Output current must be limited to 31A @ T<sub>C</sub>=25°C and 22A @ T<sub>C</sub>=80°C to not exceed the shunt specification.

① In saturation mode

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

#### Electrical Characteristics (per leg)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 500\text{V}$ ; $V_{GS} = 0\text{V}$	$T_j = 25^\circ\text{C}$			25	$\mu\text{A}$
		$V_{DS} = 400\text{V}$ ; $V_{GS} = 0\text{V}$	$T_j = 125^\circ\text{C}$			250	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10\text{V}$ , $I_D = 26\text{A}$			90	108	$\text{m}\Omega$
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 2.5\text{mA}$		2		4	$\text{V}$
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30\text{ V}$				$\pm 100$	$\text{nA}$

#### Dynamic Characteristics (per leg)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0\text{V}$ $V_{DS} = 25\text{V}$ $f = 1\text{MHz}$			7600		$\text{pF}$
$C_{oss}$	Output Capacitance				1280		
$C_{rss}$	Reverse Transfer Capacitance				620		

#### Shunt Electrical Characteristics (per leg)

Symbol	Characteristic			Min	Typ	Max	Unit
$R_{sh}$	Resistance value				20		$\text{m}\Omega$
$T_{sh}$	Tolerance				2		%
$P_{sh}$	Load capacity		$T_C=25^\circ\text{C}$			20	$\text{W}$
			$T_C=80^\circ\text{C}$			10	
$I_{sh}$	Current capacity		$T_C=25^\circ\text{C}$			31	$\text{A}$
			$T_C=80^\circ\text{C}$			22	

#### Temperature sensor PTC

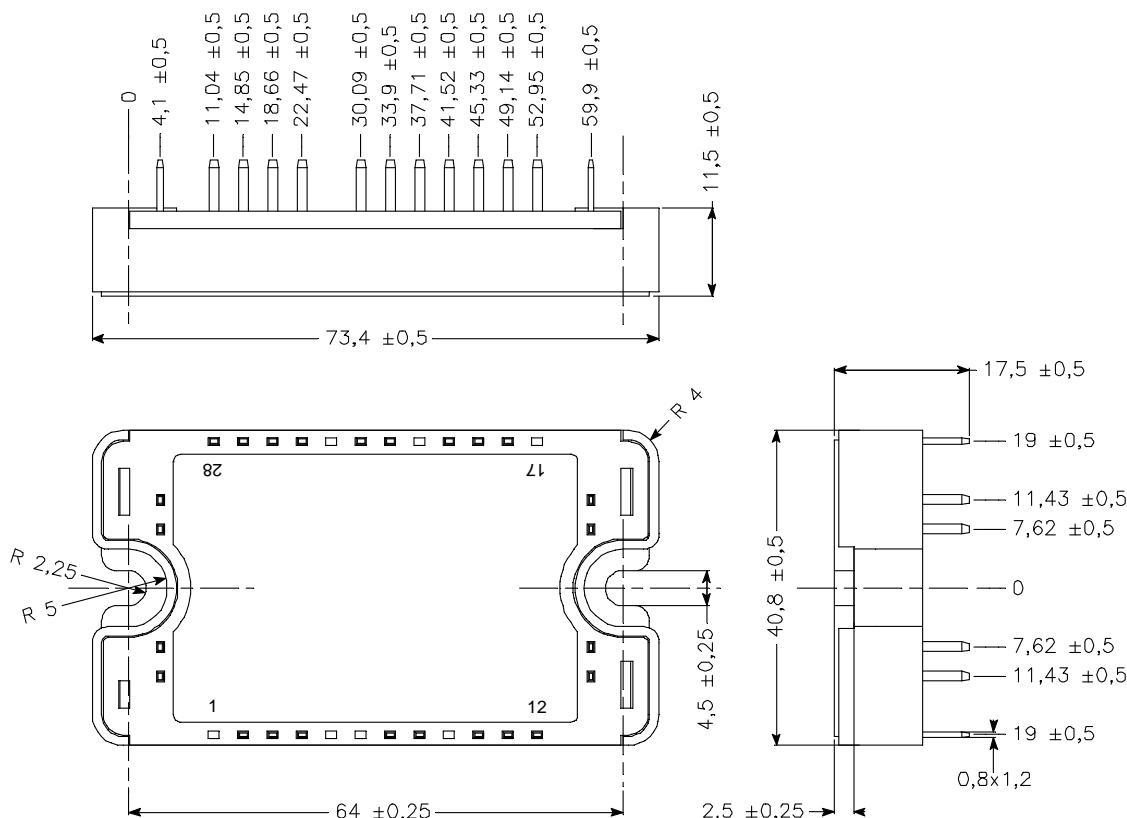
Symbol	Characteristic			Min	Typ	Max	Unit
$R_{25}$	Resistance @ $25^\circ\text{C}$			1980		2020	$\Omega$
$R_{100}/R_{25}$	Resistance ratio	$\text{Tamb}=100^\circ\text{C} & 25^\circ\text{C}$		1.676	1.696	1.716	
$R_{-55}/R_{25}$	Resistance ratio	$\text{Tamb}=-55^\circ\text{C} & 25^\circ\text{C}$		0.48	0.49	0.50	
B	Temperature coefficient				7900		$\text{ppm/K}$

#### Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance	MOSFET (per leg)				0.22	$^\circ\text{C/W}$
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, $I_{isol}<1\text{mA}$ , 50/60Hz		4000				V
$T_j$	Operating junction temperature range		-40			150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range		-40			125	
$T_c$	Operating Case Temperature		-40			100	
Torque	Mounting torque	To heatsink	M4	2.5		4.7	N.m
Wt	Package Weight					110	g

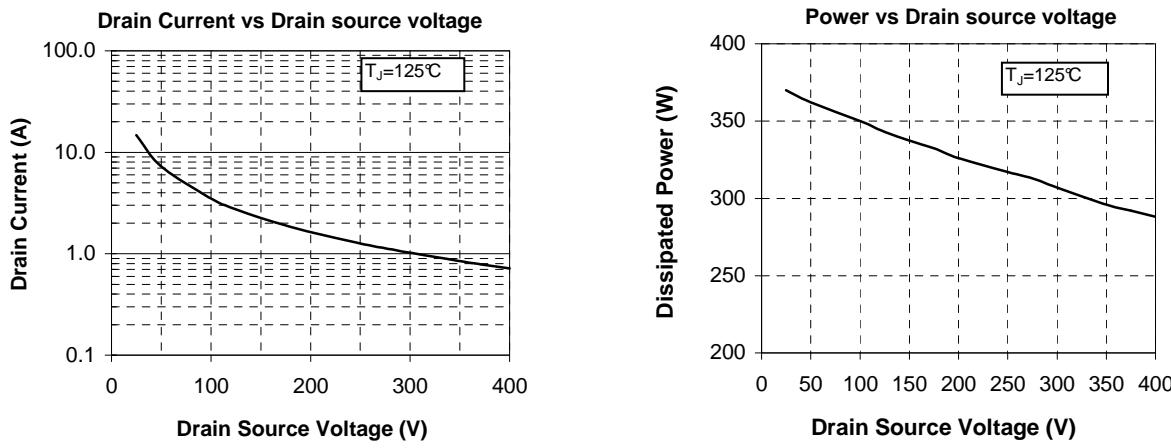


**SP3 Package outline (dimensions in mm)**



See application note 1901 - Mounting Instructions for SP3 Power Modules on [www.microsemi.com](http://www.microsemi.com)

**Typical Performance Curve (linear mode) (per leg)**



**Microsemi reserves the right to change, without notice, the specifications and information contained herein**

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